

Title (en)
GLASS SUBSTRATE WITH SLIGHTLY ROUGH LAYER

Title (de)
GLASSUBSTRAT MIT LEICHT RAUER SCHICHT

Title (fr)
SUBSTRAT VERRIER A COUCHE FAIBLEMENT RUGUEUSE

Publication
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Application
EP 12718284 A 20120330

Priority
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Abstract (en)
[origin: WO2012136919A1] The invention relates to - a glass substrate, characterized in that it is provided with a layer constituted of crystallites of at least 25 nm, covered directly with a layer constituted of crystallites of at most 10 nm; - the process for manufacturing same; - the applications thereof in a photovoltaic cell electrode, as low-emissivity glazing or in solar control.

IPC 8 full level
C03C 17/34 (2006.01); **C23C 14/00** (2006.01)

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Citation (search report)
See references of WO 2012136919A1

Citation (examination)
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• YADAV A A ET AL: "Electrical, structural and optical properties of SnO₂:F thin films: Effect of the substrate temperature", JOURNAL OF ALLOYS AND COMPOUNDS, ELSEVIER SEQUOIA, LAUSANNE, CH, vol. 488, no. 1, 20 November 2009 (2009-11-20), pages 350 - 355, XP026783646, ISSN: 0925-8388, [retrieved on 20090901], DOI: 10.1016/J.JALLCOM.2009.08.130
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